

BACHELOR OF TECHNOLOGY (CBCS) (2021-COURSE)
B. Tech. Sem - I Computer Science & Engineering : SUMMER : 2025
SUBJECT: DIGITAL ELECTRONICS

Day : Thursday
Date : 15/05/2025

S-24021-2025

Time : 10:00 AM-01:00 PM
Max. Marks : 60

N.B.

- 1) All questions are **COMPULSORY**.
- 2) Figures to the **RIGHT** indicate **FULL** marks.
- 3) Assume suitable data **WHEREVER** necessary.
- 4) Draw neat labeled diagrams **WHEREVER** necessary.

- Q.1 Convert the following** (10)
- i) $(10.25)_{10} = (?)_2$
 - ii) $(101101.10101)_2 = (?)_{16}$
 - iii) $(1505)_8 = (?)_{10}$
 - iv) $(A3E)_{16} = (?)_{10}$
- OR**
- Q.1 Explain BCD code, Gray code and Excess-3 code with suitable examples.** (10)
- Q.2 Simplify the following expressions using k-map and implement using logic gates.** (10)
 $f(A, B, C, D) = \sum m(1,5,6,7,11,12,13,15)$
- OR**
- Q.2 Simplify the following function using Quine Mc Cluskey method and implement using logic gates** $f(A, B, C, D) = \sum m(0,2,3,6,7,8,10,13)$ (10)
- Q.3 Design half adder, full adder, half subtractor and full subtractor with truth tables.** (10)
- OR**
- Q.3 Describe working of 8:1 Multiplexer with suitable circuit diagram and truth table.** (10)
- Q.4 Describe various types of flip-flops with truth table and neat diagram.** (10)
- OR**
- Q.4 Illustrate ripple counter in detail.** (10)
- Q.5 Distinguish between Moore and Mealy state machine with suitable diagram.** (10)
- OR**
- Q.5 Describe notations of ASM chart. Draw ASM chart and state diagram for 3 bit.** (10)
- Q.6 A combinational logic function is defined by** (10)
 $f_1(A, B, C) = \sum m(1,2,5)$
 $f_2(A, B, C) = \sum m(3,2,4,5)$
Implement this circuit using PLA
- OR**
- Q.6 What are semiconductor memories? Explain it with its characteristics and give classification of it.** (10)
